Quantum Hall to Insulator Transition in the Bilayer Quantum Hall Ferrom agnet

Ganpathy Murthy 1 and Subir Sachdev 2

¹D epartm ent of Physics and A stronom y, University of K entucky, Lexington KY 40506-0055

²Departm ent of Physics, Harvard University, Cambridge MA 02138

(D ated: February 20, 2024)

We describe a new phase transition of the bilayer quantum H all ferrom agnet at lling fraction = 1. In the presence of static disorder (m odeled by a periodic potential), bosonic S = 1=2 spinons can undergo a super uid-insulator transition while preserving the ferrom agnetic order. The M ott insulating phase has an emergent U (1) photon, and the transition is between H iggs and C oulom b phases of this photon. Physical consequences for charge and counter ow conductivity, and for interlayer tunneling conductance in the presence of quenched disorder are discussed.

PACS num bers: 73.50.Jt

The quantum Halle ects embody new states of matter, in which two-dimensional electron systems in a perpendicular magnetic eld B are incompressible, and exhibit excitations with fractional charge and statistics [1].

Q uantum H all system s with an internal degree of freedom, such as spin, layer index, or valley index, are richer still [2]. Because electron or hole excitations are prohibitive in energy, the low energy states can be characterized by orientation of the vector n, denoting the spin (or pseudospin in the layer index). Exchange interactions lead to ferrom agnetism, hence such system s are quantum H all ferrom agnets (QHFM 's). O f central in portance is the spin-charge relation [3, 4] in the low est Landau level (LLL), which expresses the C oulom b charge and current $(J^0;J) = J$ due to a varying con guration of n

$$J_{s} = \frac{e}{8}$$
 n (Qn Q n) (1)

The charge carriers in QHFM's are spin-textures, characterized by a topological number. In single-layer = 1 systems with spin, they are fermionic skymmions/antiskymmions[3] with charge e, while in bilayer systems they are quartonic m erons/antim erons[4] with charge e=2.

W hile our general fram ework applies to all quantum H all ferrom agnets, in this paper we focus on the bilayer quantum H all system [2, 5] at total lling factor $_{\rm T} = 1$, with an extrem ely sm all, but nonzero, tunneling am plitude h between the two layers. We will assume that real spin is frozen (which m ay not entirely be valid [6]), and spin/peudospin for us will be synonym ous with the layer index. Each layer is at half-lling. When the separation between the layers d is of the order of a magnetic length $l_0 = \frac{1}{hc=eB}$, the system is an incom pressible quantum H all state [7]. At large enough d=l₀ the system splits up into two weakly interacting, com pressible, presum ably $= \frac{1}{2}$ Ferm i-liquid-like system s [7].

D espite alm ost two decades of theory [4, 8, 9, 10, 11, 12] and experiments [13, 14], in portant aspects of the small $d=l_0$ phase are not understood. Theoretically, the small $d=l_0$ QHFM breaks symmetry at T = 0 even in the absence of an interlayer tunneling [4, 9] (spontaneous interlayer coherence) leading to a Goldstone mode [8].

This state can also be regarded as an excitonic superuid, and should exhibit a Josephson-like e ect, with

a nite interlayer current owing at strictly zero interlayer bias voltage [4, 9]. W hile there is a peak in the interlayer tunneling conductance G at zero bias [13], the peak has nite width, im plying som e intrinsic dissipation. Theoretically, interlayer tunneling should take place only within a Josephson length of the contacts [4, 15]. Thus G should be proportional to the length of the contacts, while experimentally it is seen to be proportional to the area [16]. Theoretically, there should be a T > 0Kosterlitz-Thouless transition at which the super uid sti ness has a universal jump. Experimentally [17], the zero-bias value of G (the closest analog to the super uid stiness) vanishes roughly as $(T_c - T)^3$ at the transition. It is believed [10, 18, 19, 20] that quenched disorder is ultimately responsible for these discrepancies, though a detailed understanding is lacking.

Together with H.A.Fertig, one of us has proposed a model[21] where a \coherence network" forms due to the nonperturbative e ects of disorder[22]. This model is consistent with several aspects of the experiments, notably the tunneling conductance going as the area[16] rather than the length of the sam ple, but it is classical.

In this paper we argue for a quantum phase transition to an insulating zero-tem perature phase of Q HFM, which could possibly in pact on the experimental issues discussed above. We construct a quantum low energy model at T = 0 (neglecting electron and hole excitations and keeping only smooth con gurations of n), and m in ic the nonperturbative e ects of disorder[22] by putting the system on a square lattice. We start with the imaginary time Lagrangian for a two-component quantum H all system as described by Lee and K ane(LK)[24]

$$L_{LK} = \frac{i}{4} \quad a (a + s (a) i(a) eA_0) s$$
$$+ \frac{1}{2m} jr i(a eA) s j + \frac{u}{2} s s 0^{2} (2)$$

Here the $_{\rm s}$ are the composite boson (CB) elds[23], obtained by attaching one unit of statistical ux to the electron. The gauge eld a with its Chem-Simons term in plements this transformation, while the physical (Coulomb) charge e of the CB leads to minimal coupling to the external electrom agnetic eld eA . W hen the lling is exactly = 1 ($_0 = 1=2 l_0^2$), the statistical and external elds cancel each other on average, and the CB's can Bose condense, which leads to the QH phase with a quantized Hall conductance [23]. One now decom poses [24] the CB eld into a single-com ponent charged Higgs eld , and a neutral two-com ponent unit length spinor z_s : $s = z_s$ ($z_s z_s = 1$). The spin vector em erges as $n = z \cdot z \cdot W$ e param eterize the spin sector by the variables $= n_z$ and the angle of the xy component of spin, and also add the planar anisotropy energy . A fter som e m anipulations, one obtains[24]

$$\frac{i}{4} = a (a + b_0 + b_0 + b_0) + \frac{1}{2m} jr = i(a + b + eA) j^2 + \frac{0}{2m} rn^2 + \frac{1}{2}n_z^2 (3)$$

Note that the coupling between the Higgs and spin sectors is only via the gauge-like eld

$$b = iz @ z = \frac{1}{2} @ J_s = \frac{e}{4} @ b (4)$$

The idea is to allow the periodic potential to drive the Higgs eld through a Higgs-M ott Insulator transition, while n remains ordered. Such a transition without a gauge eld is known to exist for two-component bosons on lattices [26]. The Higgs transition in single-component quantum Hall systems has been studied previously in the large-N approximation [27], and yields a second-order quantum phase transition at which the Hall conductance changes discontinuously. W e will use the sam e approach, and assume that our transition is second-order, though the question of the order remains open for the physically relevant case N = 1.

Since the transition is at xed Higgs density, it is described by a relativistic e ective theory [25].

$$L = j @ iA j2 + M2 j j2 + j j4 + \frac{i}{4} a @ a + \frac{i}{2} - + \frac{K}{2} (1 2) (r)2 + \frac{(r)2}{(1 2)} + \frac{1}{2} h cos$$

Here we have de ned A = a + beA , and allowed the spin stiness K to be renormalized down to its lowest Landau level (LLL) value (as obtained by M oon et al[4]). W e have also introduced the interlayer tunneling h, which we will take to be much smaller than any other energy scale, and will therefore neglect unless it is essential for som e physical quantity. Note that we have used the

 $z@_0 z$ term of the LK action (Eq. (3)) with h i= 0 to obtain the _term in the lagrangian. This is not only the most relevant tim e-derivative term , but has the correct dynam ics for the density-density correlations due to spin-textures to be of order q⁴ at sm all q, a requirem ent of being in the LLL. The higher tim e derivative term s com ing from integrating out high-energy modes will appear in such a combination as to not violate the LLL property. In this LLL QHFM, the 2 2 correlator of hob i (with $b_0(k)$ really standing for $B_0(k) = b_0(k)$ $\frac{1}{n^2}q$ b(k), see Going to the real frequency domain, we obtain below), for small q; ! is

$$G_{b}^{(0)}(\mathbf{k}) = \begin{array}{c} D & 0\\ 0 & F q^{2} \end{array}$$
 (6)

where D; F are constants.

Now we integrate out to obtain

$$S_{eff} = S_{CS} + dk A (k) (k)A (k)$$
 (7)

Here k = (!;q) and the polarization tensor has the gauge-invariant form

$$(k) = \frac{f(k^2)}{4k^2} (k^2 \qquad k k)$$
(8)

In the Higgs phase f is a constant, while in the Mott phase f' k^2 for k M. Going to Coulom b gauge for a (r a = 0), one can rewrite the gauge action in a 2 2 matrix form acting on a_{1} (k) and a_{T} (k) = iq a (k), where $\hat{q} = q = q$. We will make a similar decomposition for b and A. De ne $\mathcal{B}_0(k) = b_0(k)$ $\frac{\mathrm{i!}}{\mathrm{g}} \mathbf{b}_{\mathrm{L}}$ (k), with $b_{\Gamma}(k) = i\hat{q} \quad b(k) \text{ and } b(k) = i\hat{q} \quad b(k).$ Then the entries corresponding to a_0 and $a_T\,$ are \breve{b}_0 and b_T . In this 2 2 language we have

$$= \frac{1}{4} \quad \begin{array}{c} f \frac{q^2}{k^2} & 0 \\ 0 & f \end{array} \quad \begin{array}{c} c & s \\ s & = \\ \end{array} \quad \begin{array}{c} 1 & 0 & iq \\ iq & 0 \end{array} \quad (9)$$

To proceed, we de ne = + _{CS} and integrate out the gauge elds to obtain an elds to contain an elds to contain an elds to contain an elds to contain an elds to be a state of the \tilde{b}_0 $e \tilde{X}_0$ and $B_T = b_T$ eA_{T} :

$$dk B_{0}(k) B_{T}(k) \begin{bmatrix} 1 & B_{0}(k) \\ B_{T}(k) & B_{T}(k) \end{bmatrix}$$
(10)

where the matrix 0 =has the form

7.

$$Q = \frac{1}{4} \begin{bmatrix} \frac{fq^2}{f^2 + k^2} & \frac{iqf^2}{f^2 + k^2} \\ \frac{iqf^2}{f^2 + k^2} & \frac{fk^2}{f^2 + k^2} \end{bmatrix}$$
(11)

(5) In order to obtain the electrom agnetic response, one 'should now integrate out b , that is, ; . W e take account of the b Q b term in the random phase approximation (RPA) to obtain the \full" correlator (as opposed to the bare" correlator of Eq. (6).

hb (k)b (k)i=
$$G_{b_i}^{RPA} = (G_{b}^{(0)})^1 + Q^1$$
 (12)

We now integrate out b to obtain the nale ective action for the electrom agnetic potential A , which takes the form

$$S_{eff} [A] = dk \frac{e^2}{4} A (k) Q Q G_b^{RPA} Q) A (k)$$
(13)

Now we can read o the conductivity matrix from

$$P = 4 \quad Q \quad Q G_{b}^{R P A} Q = 4 \quad G_{b}^{(0)} + Q^{-1} \quad (14)$$

Re(_{xx} (q; !)) =
$$\frac{e^2}{2} \frac{!}{q^2}$$
 Im (P₀₀) (15)

$$_{xy}$$
 (q; !) = $\frac{e^2}{2} \frac{1}{q} P_{01}$ (16)

In the Higgs phase, Re($_{xx}$) vanishes below the gap f and $_{xy}$ approaches the quantized value of $e^2=2$ for !; q f denoting a quantized Hall phase. In the M ott phase the entire conductivity matrix vanishes for !; q M, denoting an insulating phase. At the critical point f = $\frac{1}{8}$ q² !², and the system has the critical conductivities

$$_{xx}(0;!) = \frac{e^2}{2} \frac{=8}{1+(=8)^2} \qquad _{xy} = \frac{1}{8} xx$$
 (17)

Going back to Eq. (12), one can nd propagating charge modes as poles of G_b^{RPA} . In the Higgs phase, one nds a propagating mode with a dispersion

$$! = {p \over q^2 (1 + D f) + f^2 = (1 + F f q^2)}$$
(18)

In the M ott phase, no propagating charge m odes exist (there are only branch cuts in the charge correlator).

Let us now turn to the spin sector. The most interesting quantity is the self-energy matrix (in ; space) $_{ab}$ near the critical point, which can be related to measurable quantities. For example Im () is related to the dissipative counter ow conductivity via

$$Re(_{CF}(q;!))' K^{2}q^{2} \frac{Im((q;!))}{![(! cq)^{2} + (Im())^{2}]}$$
(19)

and to the interlayer conductance via

$$G_{interlayer} = 2_{0}! \frac{Im ((q;!))}{[(! cq)^{2} + (Im ())^{2}]}$$
(20)

where we have absorbed the realpart of $_{ab}$ into a renormalization of the spin-wave velocity.

In the Higgsphasewe nd for smallq close to threshold ! f f

Im
$$(!;q)' q^2 f^2 (K (! f)^2 + h) (! f)$$

Im $((!;q)' q^2 f^2 (K (! f)^2 +) (! f)$
Im $(!;q)' q^2 f^2 (! f)$ (21)

where we de ne the o -diagonal term in the quadratic term of the e ective action of ; in real frequency as $(1 +)i!_{0}=2$. The main features are the presence of a threshold frequency (the gap to charge excitations) which vanishes linearly as the Higgs eld approaches criticality f ! 0, as well as a coupling which also vanishes as a power of f. Note the qualitative di erence made in Im by the presence of h.

At the large-N critical point we nd

Im
$$(!^{7};q^{7}): h = 0$$
 (22)
 $(!^{5};q^{5}): h \in 0$ (23)

Here we see that powers of f have been replaced by powers of !; q, with one extra power appearing due to the branch cut. Let us discuss nite-T properties brie y. Starting in the Higgs phase, if one goes to nozero T f the system is quantum critical[28] and we can expect to see the above behavior with ! ! T. Also, in the presence of quenched disorder, we can expect (in addition to the activated contribution due to the tunneling of merons[21]) a power-law contribution in T to all physical quantities in the quantum critical regime.

Consider now the qualitative behavior of the interlayer conductance G for T h, believed to be true of experimental samples at millikely in temperatures. For T f we expect the interlayer tunneling to be incoherent, which is consistent with the nite width of the zero-bias peak seen in experiments. With quenched disorder there may be a Higgs glass phase (see below) with gapless charge uctuations, which would im ply incoherent interlayer tunneling for any nonzero T.

Finally, deep in the M ottp phase, there is again a threshold frequency ! th (q) = $\frac{p + q^2}{4M^2 + q^2}$.

Im (!;q) (!
$$l_{\rm th}$$
)⁴q² (! ! $l_{\rm th}$) (24)

The addition of the long-range Coulomb interaction to the action m akes no qualitative di erence to the above.

Let us now comment on previous related work. Some authors have argued for an XY spin-glass phase at su cient disorder[21, 29] but these arguments are for the classical model. There are also proposals that the ground state at T = 0 is a gauge-glass[10, 19] which is still a quantum H all phase, but with power-law X Y order. O ther authors have argued for a spontaneous breaking of translation invariance[30]: Like the quantum H all-W igner crystal transition this likely occurs at large in balance[30]. Finally, som e authors have argued for a translation-invariant Q H phase with no long-range order in n [31]. In our model, we assume that the X Y ferrom agnetism is robust across the Higgs transition which is driven by a periodic potential (a proxy for disorder), which di ers from all the above proposals.

In the presence of static disorder, a key feature of our m odel is that the dissipation arises not directly from disorder coupled to the X Y order param eter[32], but rather from the disorder inducing a phase transition which creates a phase with dynam ical low energy spinon and charge excitations coupled to the X Y m odes. W e call this phase a H iggs glass, in analogy to the B ose glass[25] and gauge glass[10, 19] phases. The H iggs glass di ers from the gauge glass in having dynam ical, gapless gauge uctuations. W e expect that there will be an imperfect charge- ux relation in the H iggs glass phase, which will allow us to infer gapless charge uctuations with perhaps a vanishing density of states at vanishing energy.

In conclusion, we have studied a lowest Landau level model for the = 1 bilayer quantum Hall ferrom agnet which displays a Higgs! Mott transition of spinons in the presence of a periodic potential. Our understanding of the M ott phase of the spinons, which is also a ferrom agnetic insulator, remains incomplete. The standard expectation is that the large $d=l_0$ bilayer system is best

described in terms of two species of weakly interacting C om posite Ferm ions (CF's) [11]. It is possible that the transition we have described on the lattice is preempted by a rst-order transition (reverting to second-order with quenched disorder) to a phase adiabatically connected to two decoupled species of CF's.

The framework we have sketched should apply to the single layer QHFM with spin, where the existence of charge uctuations below the Zeem an energy is not

- K. von K litzing, G. Dorda, and M. Pepper, Phys. Rev. Lett. 45, 494 (1980); D. C. T sui, H. L. Stom er, and A. C. Gossard, Phys. Rev. Lett. 48, 1559 (1982); R. B. Laughlin, Phys. Rev. Lett. 50, 1395, (1983); J. K. Jain, Phys. Rev. Lett. 63, 199, (1989).
- [2] See S.M.G irvin and A.H.M acD onald in Perspectives on Quantum HallE ects, S.DasSarma and A.Pinczuk, Editors (W iley Interscience, New York, 1997).
- [3] S.L. Sondhi, A. Karlhede, S.A. Kivelson, and E.H. Rezayi, Phys. Rev. B 47, 16419 (1993).
- [4] K. Yang, K. Moon, L. Zheng, A. H. MacDonald, S. M. Girvin, D. Yoshioka, and S.-C. Zhang, Phys. Rev. Lett. 72, 732 (1994); K. Moon, H. Mori, K. Yang, S. M. Girvin, A. H. MacDonald, L. Zheng, D. Yoshioka, and S.-C. Zhang, Phys. Rev. B 51, 5138 (1995).
- [5] See J.P. E isenstein and A.H. M add onald, Nature 432, 691 (2004) and references therein.
- [6] N.Kum ada, K.Muraki, K.Hashim oto, and Y.Hirayama, Phys.Rev.Lett. 94, 096802 (2005); I.B. Spielm an, L.A. Tracy, J.P.Eisenstein, L.N.Pfei er, and K.W. West, Phys.Rev.Lett. 94, 076803 (2005); S.Luin, V.Pellegrini, A.Pinczuk, B.S.Dennis, L.N.Pfei er, anfK.W. West, Phys.Rev.Lett. 94, 146804 (2005).
- [7] S. Q. Murphy, J. P. Eisenstein, G. S. Boebinger, L. N. Pfeier, and K. W. West, Phys. Rev. Lett. 72, 728 (1994).
- [8] H.A.Fertig, Phys. Rev. B 40, 1087 (1989).
- [9] X G.W en and A.Zee, Phys.Rev.Lett. 69, 1811 (1992);
 Phys. Rev. B. 47, 2265 (1993); Z F. Ezawa and A. Iwazaki, Phys.Rev.B 47, 7295 (1993).
- [10] L.Balents and L.Radzihovsky, Phys.Rev.Lett.86, 1825
 (2001); A.Stem, SM.Girvin, A.H.MacDonald, and Ning Ma, Phys.Rev.Lett.86, 1829 (2001).
- [11] Y.B.Kim, C.Nayak, E.Demler, N.Read, and S.Das Samma, Phys. Rev. B 63, 205315 (2001).
- [12] Z.W ang, Phys. Rev. Lett. 92, 136803 (2004).
- [L3] I.B.Spielm an, J.P.Eisenstein, L.N.P fei er, and K.W. West, Phys.Rev.Lett. 84, 5808 (2000).
- [14] I.B. Spielm an, J.P. E isenstein, L.N. P fei er, and P hys. Rev. Lett. 93, 036801 (2004); E. Tutuc, M. Shayegan, and D. Huse, P hys. Rev. Lett. 93, 036802 (2004).
- [15] E.Rossi, A.S.Nunez, and A.H.M adD onald, Phys. Rev. Lett. 95, 266804 (2005).
- [16] A.D.K.Finck, A.R.Champagne, J.P.Eisenstein, L.N. Pfeier, and K.W.West, Bull. Am. Phys. Soc., J37.4 (2008).

understood [33].

It is a pleasure for G M to thank Herb Fertig, Z iqiang W ang, Steve G irvin, and T. Senthil for illum inating discussions, and the A spen C enter for Physics where some of this work was conceived. G M also deeply appreciates the hospitality of the Physics D epartment at H arvard U niversity, where this work was carried out. W e would like to acknow ledge partial support from the N SF under DM R-0703992 (GM) and DM R-0757145 (SS).

- [17] A. R. Cham pagne, J. P. Eisenstein, L. N. Pfei er, and K.W. West, Phys. Rev. Lett. 100, 096801 (2008).
- [18] H. A. Fertig, Phys. Rev. Lett. 89, 035703 (2002);
 H. A. Fertig and Joseph P. Straley, Phys. Rev. B. 66, 201402 (R) (2002); Phys. Rev. Lett. 91, 046806 (2003).
- [19] D.Sheng, L.Balents, and Z.W ang, Phys. Rev. Lett. 91, 116802 (2003).
- [20] D A.Huse, cond-m at/0407452 (2004).
- [21] H.A. Fertig and G.M urthy, Phys. Rev. Lett. 95, 156802 (2005); Sol. State. Commun. 140, 83 (206).
- [22] A. L. E fros, Sol. St. Commun. 65, 1281 (1988); A. L. E fros, F. G. Pikus, and V. G. Burnett, Phys. Rev. B 47, 2233 (1993).
- [23] S.-C. Zhang, H. Hansson, and S.A. Kivelson, Phys. Rev. Lett. 62, 82 (1989); D.-H. Lee and S.-C. Zhang, Phys. Rev. Lett. 66, 1220 (1991).
- [24] D.H. Lee and C.L. Kane, Phys. Rev. Lett. 64, 1313 (1990).
- [25] M.P.A.Fisher, P.B.W eichm ann, G.Grinstein, and D. S.Fisher, Phys. Rev. B 40, 546 (1989).
- [26] K. Sheshadri, H. R. Krishnam urthy, R. Pandit, and T. V. Ram akrishnan, Europhys.Lett.22, 257 (1993); E. Altman, W. Hofstetter, E. Dem ler, and M. D. Lukin, New Jour.Phys.5, 113.1 (2003); A. B. Kuklov and B. V. Svistunov, Phys.Rev.Lett.90, 100401 (2003); A. B. Kuklov, N. Prokof'ev, and B. V. Svistunov, Phys.Rev.Lett.92, 030403 (2004).
- [27] W. Chen, M. P.A. Fisher, and Y.-S.Wu, Phys. Rev. B 48, 13749 (1993); X.-G.Wen and Y.-S.Wu, Phys. Rev. Lett. 70, 1501 (1993); L.P. Pryadko and S.-C. Zhang, Phys. Rev. B 54, 4953 (1996); J. Ye and S. Sachdev, Phys. Rev. Lett. 80, 5409 (1996).
- [28] S. Sachdev, Quantum Phase Transitions (Cambridge University Press, New York 1999)
- [29] J. Rapsch, D. K. Lee, and J. T. Chalker, Phys. Rev. Lett. 88, 036801 (2002); D. K. Lee, S. Rapsch, and J. T. Chalker, Phys. Rev. B 67, 195322 (2003).
- [30] K. Yang, Phys. Rev. Lett. 87, 056802 (2001); J. Ye and L. Jiang, Phys. Rev. Lett. 98, 236802 (2007).
- [31] R. L. Doretto, A. O. Caldeira, and C. Morais Smith, Phys. Rev. Lett. 97, 1876401 (2006); Z. Papic, and M.
 V. Milovanovic, Phys. Rev. B 75, 195304 (2007).
- [32] S.John and M.J.Stephen, Phys. Rev. B 28, 6358 (1983); A.G.Green, Phys. Rev. Lett. 82, 5104 (1999).
- [33] A.G.Green, Phys. Rev. B 57, R 9373 (1998).